





25V PNP LOW SATURATION TRANSISTOR IN SOT23

Features

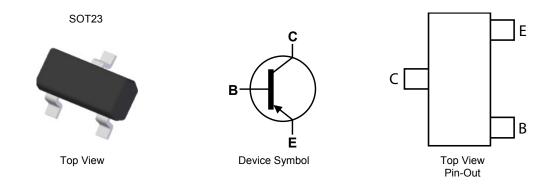
- BV_{CEO} > -25V
- BV_{CEO} > -35V forward blocking voltage
- I_C = -3A Continuous Collector Current
- Low Saturation Voltage, V_{CE(SAT)} < -150mV @ -1A.
- $R_{CE(sat)} = 87m\Omega$ for a low equivalent on-resistance
- 725mW power dissipation
- h_{EE} characterised up to -6A for high current gain hold-up
- Complementary NPN Type: ZXTN649F
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- · Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ³
- Weight 0.008 grams (approximate)

Application

- MOSFET gate drivers
- Power switching in automotive and industrial applications
- Motor drive and control



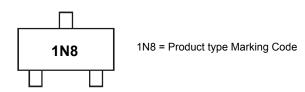
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP749FTA	1N8	7	8	3,000

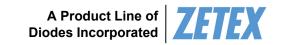
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com

Marking Information







Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-35	V
Collector-Emitter Voltage	V_{CEO}	-25	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-3	Α
Peak Pulse Current	I _{CM}	-6	Α
Base Current	lΒ	-500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

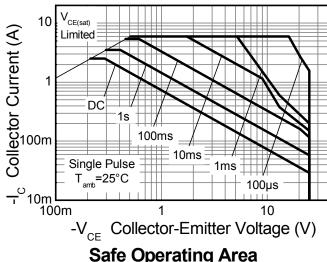
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	725	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	172	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{\theta JL}$	79	°C/W
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C

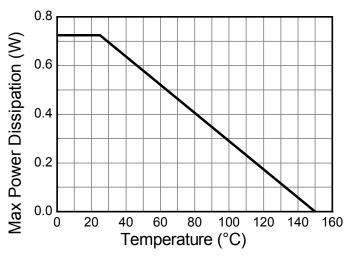
Notes:

^{5.} For a device surface mounted on 15mm X 15mm X 1.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.6. Thermal resistance from junction to solder-point (at the end of the collector lead).



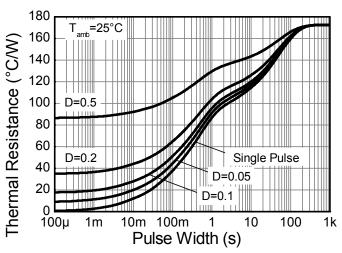
Thermal Characteristics and Derating information



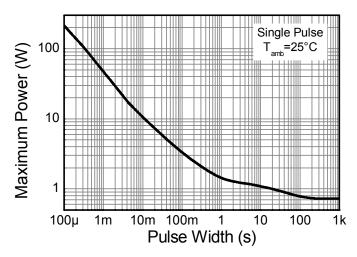


Safe Operating Area





Derating Curve



Transient Thermal Impedance

Pulse Power Dissipation





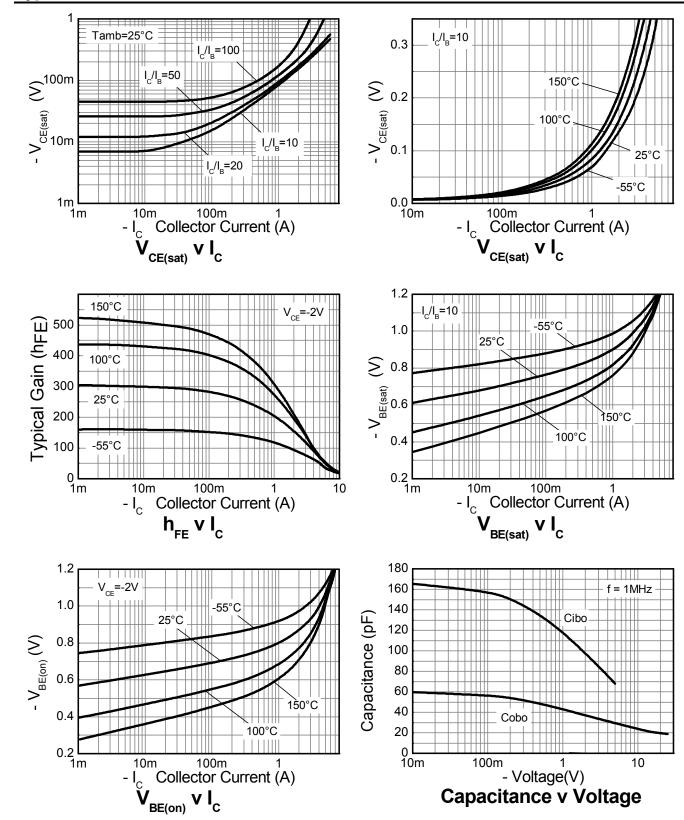
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-35	-60	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	-25	-40	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.4	-	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	-	<1	-50 -0.5	nΑ μΑ	V _{CB} = -28V V _{CB} = -28V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	-	<1	-50	nA	V _{EB} = -5.6V
Static Forward Current Transfer Ratio (Note 7)	h _{FE}	200 130 100 25	320 230 180 50	500 - - -	1	I_C = -100mA, V_{CE} = -2V I_C = -1A, V_{CE} = -2V I_C = -2A, V_{CE} = -2V I_C = -6A, V_{CE} = -2V
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	-	-85 -229	-150 -350	mV	I _C = -1A, I _B = -100mA I _C = -3A, I _B = -300mA
Base-Emitter Turn-On Voltage (Note 7)	$V_{BE(on)}$	-	-786	-850	mV	I _C = -1A, V _{CE} = -2V
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	-	-895	-1000	mV	I _C = -1A, I _B = -100mA

Notes: 7. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

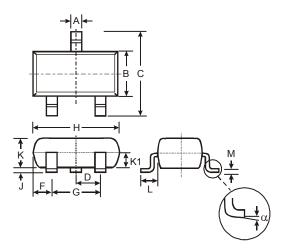






Package Outline Dimensions

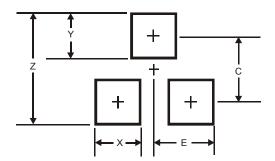
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	-	0.400		
L	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
С	2.0
Е	1.35





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